







## LITTLITY PATENT APPLICATION

	LICATION
SCANNED QA.	PATENT DATE

					EXAMINER	
APPLICATION NO.	CONT/PRIOR	CLASS	SUBCLASS	ART UNIT	EXAMINED	124-3AL/
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09/008525	<b>'</b>	201	i			

CHANG-JIN KANG JUN-YONG NOH YOUNG-WOO KANG

SEMICONDUCTOR MEMORY DEVICE AND METHOL OF MANUFACTURING FOR PREVENTING BIT LINE OXIDATION

PTO-2040 12/99

## PREPARED AND APPROVED FOR ISSUE

		issuing Cl	_ASSIFICATION					
ORIG	INAL		CROSS REFERENCE(S)					
CLASS SUBCLASS		CLASS	SUBCLASS (ONE SUBCLASS PER BLOCK)					
NTERNATIONAL	CLASSIFICATION							
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TERMINAL		DRAWINGS		CLAIMS ALLOWED	
DISCLAIMER	Sheets Drwg.	Figs. Drwg.	Print Fig.	Total Claims	Print Claim for O.G.
· \			ľ	_	
a) The term of this patent				NOTICE OF ALL	OWANCE MAILED
subsequent to (date) has been disclaimed.	(Assistant Examiner) (Date)				
b) The term of this patent shall					
not extend beyond the expiration date of U.S Patent. No.				ISSUE FEE	
	İ			Amount Due	Date Paid
	(Primary	Examiner)	(Date)		
				ISSUE BA	TCH NUMBER
c) The terminalmonths of this patent have been disclaimed.	(Legal Instrum	ents Examiner)	(Date)		

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(LABEL AREA)